IN THE CLAIMS

Claim 1. (Currently Amended) A display device having a plurality of pixels arrayed so as to form a matrix-like pattern, wherein

the display device comprises

~~a light-emitting element~~ an organic electroluminescence element that is formed in a longitudinally oblong shape in each pixel,

a drive thin-film transistor that is formed in each pixel and that feeds a current to the ~~light-emitting element~~ organic electroluminescence element to make the ~~light-emitting element~~ organic electroluminescence element emit light, and

a control thin-film transistor that controls operation of the drive thin-film transistor,

the drive thin-film transistor is formed in a laterally oblong shape ~~and is arranged with a length direction thereof perpendicular to a length direction of the light-emitting element~~,

a gate signal line and a source signal line connected to the control thin-film transistor are arranged in a matrix-like pattern,

the organic electroluminescence element is arranged so that a length direction thereof is parallel to the source signal line,

the drive thin-film transistor has a channel region formed in an elongate shape,

the channel region is arranged so that a length direction thereof is parallel to the gate signal line, and

the drive thin-film transistor and the control thin-film transistor have a semiconductor layer formed of amorphous silicon.

Claim 2. (Cancelled)

Claim 3. (Canceled)

Claim 4. (Canceled)

Claim 5. (Original) A display device as claimed in claim 1, wherein,

of a source electrode and a drain electrode of the drive thin-film transistor, one is formed in a rectilinear shape and the other is formed in a shape surrounding the one.

Claim 6. (Original) A display device as claimed in claim 1, wherein

the drive thin-film transistor has a U-shaped source electrode and a drain electrode located between two fork-like portions of the U-shaped source electrode.

Claim 7. (Currently Amended) A display device as claimed in claim 1, wherein

for each row of the matrix-like pattern are formed

a gate signal line that is connected to gate electrodes of all control thin-film transistors in pixels located in the row, and

a power feed line that is arranged substantially parallel to the gate signal line, and from which a current is fed via drive thin-film transistors to the ~~light-emitting elements~~ organic electroluminescence elements in the row,

for each column of the matrix-like pattern is formed

a source signal line that is connected to source electrodes of all control thin-film transistors in pixels located in the column and that crosses the gate signal line, and

within each area surrounded by gate signal lines and source signal lines, the ~~light-emitting element~~ organic electroluminescence element, the drive thin-film transistor, the power feed line, and the control thin-film transistor are arranged in this order along the source signal line as seen in a plan view.

Claim 8. (Original) A display device as claimed in claim 7, wherein

between the drive thin-film transistor and the control thin-film transistor is formed a holding capacitor of which one electrode is shared as the power feed line and of which the other electrode is formed by an auxiliary electrode that connects to the drain electrode of the control thin-film transistor, and

the auxiliary electrode is electrically connected to the gate electrode of the drive thin-film transistor.

Claim 9. (Currently Amended) A display device as claimed in claim 7, wherein

the display device comprises ~~light-emitting elements~~ organic electroluminescence elements that emit light of different colors,

a plurality of power feed lines are formed so as to correspond to light of the different colors,

the plurality of power feed lines are arranged between the drive thin-film transistor and the control thin-film transistor within a same pixel, and

the ~~light-emitting elements~~ organic electroluminescence elements are fed with a current from the corresponding power feed lines.

Claim 10. (Original) A display device as claimed in claim 7, wherein

the gate signal line is used as the gate electrode of the control thin-film transistor, and

the control thin-film transistor is formed above the gate signal line.

Claim 11. (Currently Amended) ~~A display device as claimed in claim 1, wherein~~ A display device having a plurality of pixels arrayed so as to form a matrix-like patter, wherein

the display device comprises

an organic electroluminescence element that is formed in a longitudinally oblong shape in each pixel,

a drive thin-film transistor that is formed in each pixel and that feds a current to the organic electroluminescence element to make the organic electroluminescence element emit light, and

a control thin-film transistor that controls operation of the drive thin-film transistor,

the drive thin-film transistor is formed in a laterally oblong shape, and is arranged with a length direction thereof perpendicular to a length direction of the organic electroluminescence element,

the drive thin-film transistor and the control thin-film transistor have a semiconductor layer formed of amorphous silicon,

a bank layer is arranged around the ~~light-emitting element~~ organic electroluminescence element,

the bank layer is formed so as to overlap the drive thin-film transistor,

a cut is formed in the bank layer between the ~~light-emitting element~~ organic electroluminescence element and the drive thin-film transistor, and

a light-shielding film is formed on the bank layer at least in a portion thereof near the cut.

Claim 12. (Currently Amended) A display device as claimed in ~~claim 1~~ claim 11, wherein

~~a bank layer is arranged around the light-emitting element,~~

the bank layer is formed so as to overlap the control thin-film transistor,

a cut is formed in the bank layer between the ~~light-emitting element~~ organic electroluminescence element and the control thin-film transistor formed in a next pixel, and

a light-shielding film is formed on the bank layer at least in a portion thereof near the cut.

Claim 13. (Canceled)

Claim 14. (Currently Amended) A display device as claimed in one of ~~claims 11 to 13~~ claim 11 or claim 12, wherein

the display device further comprises

a pixel electrode that is arranged below a light-emitting layer of the ~~light-emitting element~~ organic electroluminescence element and that connects to the drive thin-film transistor, and

a common electrode that is arranged so as to face the pixel electrode with the light-emitting layer interposed in between and that covers the bank layer, and

the light-shielding film is formed by the common electrode.

Claim 15. (Currently Amended) A display device as claimed in one of claims ~~1 and 3 to 13~~ 1 and 5 to 12,

wherein the drive thin-film transistor and the control thin-film transistor are of an n-channel type.

Claim 16. (Currently Amended) A display device as claimed in one of claims ~~1 and 3 to 13~~ 1 and 5 to 12, wherein the drive thin-film transistor and the control thin-film transistor are of a p-channel type.

17. (Canceled)